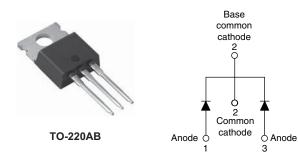


Vishay Semiconductors

# Ultrafast Rectifier, 2 x 10 A FRED Pt®



PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 10 A				
$V_{R}$	200 V				
V <sub>F</sub> at I <sub>F</sub>	See Electrical table				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				

#### **FEATURES**

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature



- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level





ROHS

#### **DESCRIPTION/APPLICATIONS**

VS-MUR2020CTPbF is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage		$V_{RRM}$		200	V		
Average rectified forward current	per leg	I <sub>F(AV)</sub>		10			
Average rectified forward current	total device		Rated V <sub>R</sub> , T <sub>C</sub> = 145 °C	20	Α		
Non-repetitive peak surge current per leg		I <sub>FSM</sub>		100	A		
Peak repetitive forward current per leg		I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 145 °C	20			
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-		
Forward voltage V <sub>F</sub>		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	-	0.85	V	
	$V_{F}$	I <sub>F</sub> = 16 A	-	-	1.15		
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 125 °C	-	-	1.05		
Davaga laskaga ayuwant		$V_R = V_R$ rated	-	-	15		
Reverse leakage current I <sub>R</sub>		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	250	μΑ	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	55	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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## VS-MUR2020CTPbF

# Vishay Semiconductors Ultrafast Rectifier, 2 x 10 A FRED Pt®



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1.0 \text{ A, } dI_F/dt =$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	35		
	+	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>REC</sub> = 0.25 A		-	-	25	no	
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 10 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	21	-	ns	
		T <sub>J</sub> = 125 °C		-	35	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.9	-	Α	
		T <sub>J</sub> = 125 °C		-	4.8	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		ı	25	-	nC	
		T <sub>J</sub> = 125 °C		-	78	-	IIC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C	
Thermal resistance, per leg	C		-	-	2.5		
junction to case total device	$R_{thJC}$		-	-	1.25		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-		
Maight			-	2.0	-	g	
Weight			-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-220AB		MUR2	020CT	•	



# Ultrafast Rectifier, 2 x 10 A FRED Pt® Vishay Semiconductors

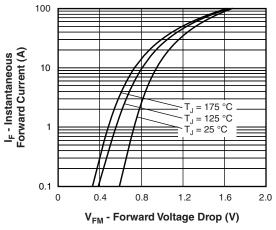


Fig. 1 - Maximum Forward Voltage Drop Characteristics

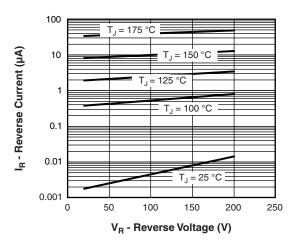


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

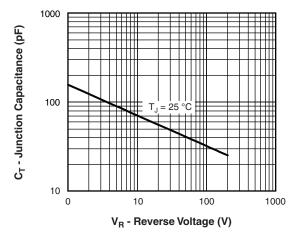


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

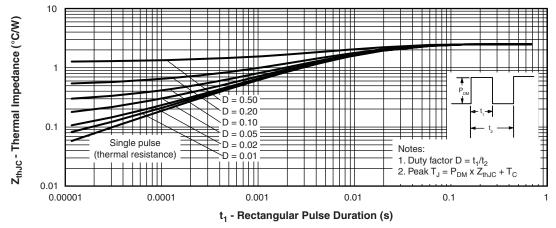


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

## Vishay Semiconductors Ultrafast Rectifier, 2 x 10 A FRED Pt®



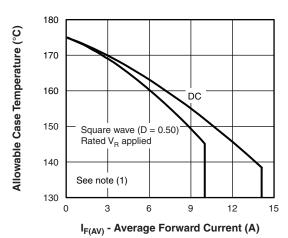


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

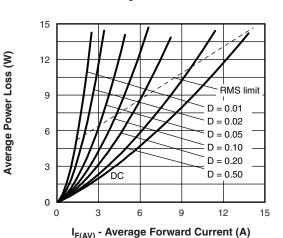


Fig. 6 - Forward Power Loss Characteristics

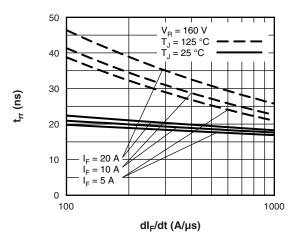


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

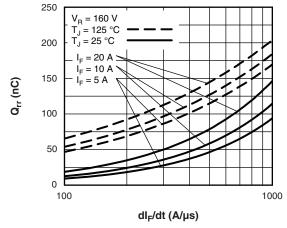


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \mbox{(1)} & \mbox{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \mbox{Forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6)}; \\ \end{array}$  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$ 



# Ultrafast Rectifier, 2 x 10 A FRED Pt® Vishay Semiconductors

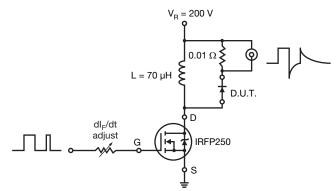
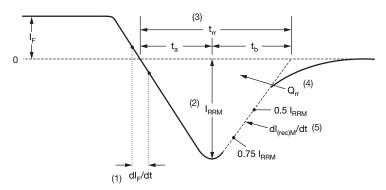


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>E</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.
- (4) Q<sub>rr</sub> area under curve defined by t<sub>rr</sub> and I<sub>RRM</sub>

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

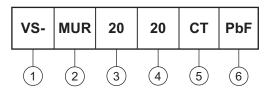
Fig. 10 - Reverse Recovery Waveform and Definitions

## Vishay Semiconductors Ultrafast Rectifier, 2 x 10 A FRED Pt®



## **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Ultrafast MUR series

3 - Current rating (20 = 20 A)

4 - Voltage rating (20 = 200 V)

5 - CT = Center tap (dual)

6 - PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

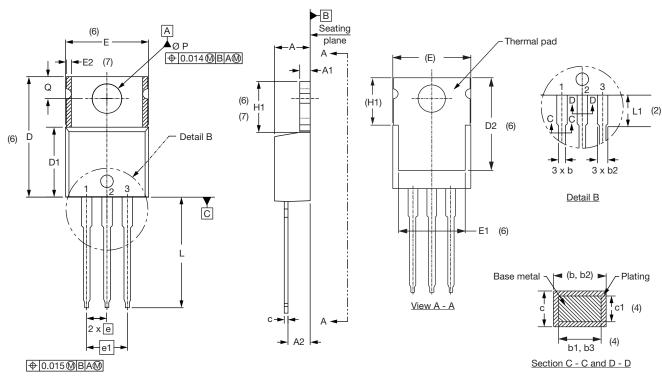
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Part marking information <u>www.vishay.com/doc?95225</u>					
SPICE model	www.vishay.com/doc?95272				



## Vishay Semiconductors

## **TO-220AB**

#### **DIMENSIONS** in millimeters and inches



## Lead assignments

### **Diodes**

- 1. Anode/open
- 2. Cathode
- 3. Anode

#### Conforms to JEDEC outline TO-220AB

MILLIN	IETERS	INCHES		NOTES
MIN.	MAX.	MIN.	MAX.	NOTES
4.25	4.65	0.167	0.183	
1.14	1.40	0.045	0.055	
2.56	2.92	0.101	0.115	
0.69	1.01	0.027	0.040	
0.38	0.97	0.015	0.038	4
1.20	1.73	0.047	0.068	
1.14	1.73	0.045	0.068	4
0.36	0.61	0.014	0.024	
0.36	0.56	0.014	0.022	4
14.85	15.25	0.585	0.600	3
8.38	9.02	0.330	0.355	
11.68	12.88	0.460	0.507	6
	MIN. 4.25 1.14 2.56 0.69 0.38 1.20 1.14 0.36 0.36 14.85 8.38	4.25     4.65       1.14     1.40       2.56     2.92       0.69     1.01       0.38     0.97       1.20     1.73       1.14     1.73       0.36     0.61       0.36     0.56       14.85     15.25       8.38     9.02	MIN.         MAX.         MIN.           4.25         4.65         0.167           1.14         1.40         0.045           2.56         2.92         0.101           0.69         1.01         0.027           0.38         0.97         0.015           1.20         1.73         0.047           1.14         1.73         0.045           0.36         0.61         0.014           0.36         0.56         0.014           14.85         15.25         0.585           8.38         9.02         0.330	MIN.         MAX.         MIN.         MAX.           4.25         4.65         0.167         0.183           1.14         1.40         0.045         0.055           2.56         2.92         0.101         0.115           0.69         1.01         0.027         0.040           0.38         0.97         0.015         0.038           1.20         1.73         0.047         0.068           1.14         1.73         0.045         0.068           0.36         0.61         0.014         0.024           0.36         0.56         0.014         0.022           14.85         15.25         0.585         0.600           8.38         9.02         0.330         0.355

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
E2	-	0.76	-	0.030	7	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6, 7	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØΡ	3.54	3.73	0.139	0.147		
Q	2.60	3.00	0.102	0.118		
θ	90° t	o 93°	90° to 93°			
	•					

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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Lead tip

## **Legal Disclaimer Notice**



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